# UNISONIC TECHNOLOGIES CO., LTD

### 2SA1694

#### PNP EPITAXIAL SILICON TRANSISTOR

## SILICON PNP EPITAXIAL PLANAR TRANSISTOR

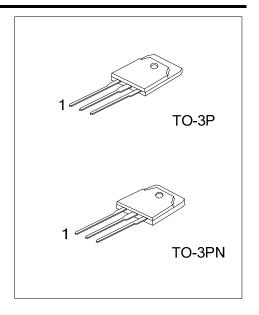
#### DESCRIPTION

The UTC **2SA1694** is a silicon PNP epitaxial planar transistor, it uses UTC's advanced technology to provide the customers with high DC current gain and high collector-base breakdown voltage, etc.

The UTC **2SA1694** is suitable for audio and general purpose, etc.

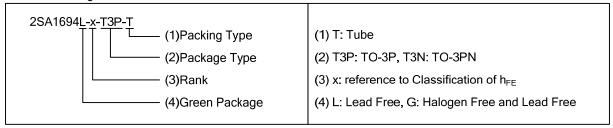
#### ■ FEATURES

- \* High DC current gain
- \* High collector-base breakdown voltage

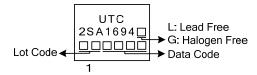


#### ■ ORDERING INFORMATION

Ordering	Ordering Number		Pin Assignment			Dooking
Lead Free	Halogen Free	Package	1	2	3	Packing
2SA1694L-x-T3P-T	2SA1694G-x-T3P-T	TO-3P	В	С	Е	Tube
2SA1694L-x-T3N-T	2SA1694G-x-T3N-T	TO-3PN	В	С	Е	Tube



#### ■ MARKING



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#### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	$V_{CBO}$	-120	V
Collector-Emitter Voltage	$V_{CEO}$	-120	V
Emitter-Base Voltage	$V_{EBO}$	-6	V
Collector Current	Ic	-8	Α
Base Current	I <sub>B</sub>	-3	Α
Collector Power Dissipation (T <sub>C</sub> =25°C)	Pc	80	W
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

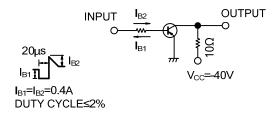
#### ■ **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-Off Current		I <sub>CBO</sub>	V <sub>CB</sub> =-120V			-10	μΑ
Emitter Cut-Off Current		I <sub>EBO</sub>	V <sub>EB</sub> =-6V			-10	μΑ
Collector-Emitter Breakdov	vn Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =-50mA	-120			V
DC Current Gain		h <sub>FE</sub>	V <sub>CE</sub> =-4V, I <sub>C</sub> =-3A	50		180	
Collector-Emitter Saturatio	n Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> =-3A, I <sub>B</sub> =-0.3A			-1.5	V
Current Gain Bandwidth Pr	roduct	f <sub>T</sub>	V <sub>CE</sub> =-12V, I <sub>E</sub> =0.5A		20		MHz
Output Capacitance		Cob	V <sub>CB</sub> =-10V, f=1MHz		300		pF
	Turn-on time	ton	V <sub>CC</sub> =-40V, R <sub>L</sub> =10Ω, I <sub>C</sub> =-4A, I <sub>B1</sub> =0.4A I <sub>B2</sub> =0.4A		0.14		μS
Switching time	Storage time	ts			1.40		μS
	Fall time	t <sub>F</sub>			0.21		μS

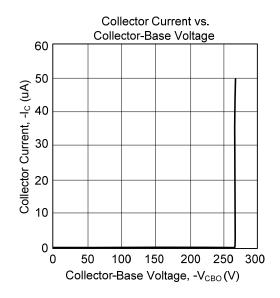
#### ■ CLASSIFICATION OF h<sub>FE</sub>

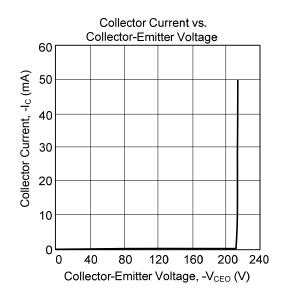
RANK	0	Р	Υ	
RANGE	50~100	70~140	90~180	

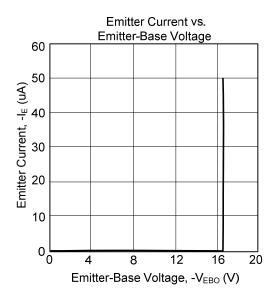
#### ■ TEST CIRCUIT

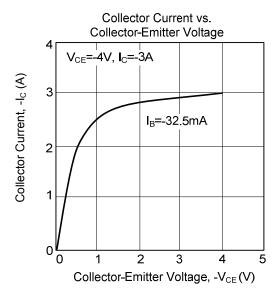


#### **■ TYPICAL CHARACTERISTICS**









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